NSN 5961-01-123-0786

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-123-0786
Inclosure Material:
Metal
Overall Length:
0.555 inches
Overall Diameter:
1.625 inches
End Application:
5840-01-105-4656
Internal Configuration:
Junction contact
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
20.00 milliamperes forward current, total rms preset
Special Features:
current; junction pattern arrangement: pnpn
Terminal Type And Quantity:
1 tab, solder lug and 2 ferrule
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0